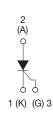
VS-12TTS08PbF, VS-12TTS08-M3

Vishay Semiconductors

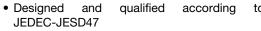
High Voltage Phase Control Thyristor, 12 A

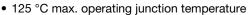


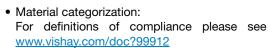


PRODUCT SUMMARY				
Package	TO-220AB			
Diode variation	Single SCR			
I _{T(AV)}	8 A			
V _{DRM} /V _{RRM}	800 V			
V_{TM}	1.2 V			
I _{GT}	15 mA			
T _J	- 40 °C to 125 °C			

FEATURES











ROHS COMPLIANT HALOGEN FREE Available

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-12TTS08... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	13.5	17	А		

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	RAMETER TEST CONDITIONS VALUES		UNITS	
I _{T(AV)}	Sinusoidal waveform	8	٨	
I _{T(RMS)}		12.5	A	
V _{DRM} /V _{RRM}		800	V	
I _{TSM}		110	A	
V _T	8 A, T _J = 25 °C	1.2	V	
dV/dt		150	V/µs	
dl/dt		100	A/μs	
T _J	Range	- 40 to 125	°C	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
VS-12TTS08PbF, VS-12TTS08-M3	800	800	1.0		



VS-12TTS08PbF, VS-12TTS08-M3

Vishay Semiconductors

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T 100 °C 100° conduction half sine ways	8	
Maximum RMS on-state current	I _{T(RMS)}	T _C = 108 °C, 180° conduction, half sine wave	12.5	
Maximum peak, one-cycle,	,	10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C	95	Α
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied, T _J = 125 °C	110	
Maximum 12t for fucing	l ² t	10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C	45	A ² s
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied, T _J = 125 °C		A-s
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C	640	A ² √s
Maximum on-state voltage drop	V _{TM}	8 A, T _J = 25 °C	1.2	V
On-state slope resistance	r _t	T 105 °C	16.2	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C	0.87	V
Maximum reverse and direct leakage	1 /1	T _J = 25 °C	0.05	
current	I _{RM} /I _{DM}	$\frac{V_{R} = \text{Rated V}_{RRM}/V_{DRM}}{V_{R} = \text{Rated V}_{RRM}/V_{DRM}}$	1.0	
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C	30	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C	50	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80 ^{\circ}\text{C, } V_{DRM} = R_g ^{-}\text{k} = \text{Open}$	150	V/µs
Maximum rate of rise of turned-on current	dl/dt		100	A/µs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P_{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	V	
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20		
		Anode supply = 6 V, resistive load, T _J = 25 °C	15	mA	
119901		Anode supply = 6 V, resistive load, T _J = 125 °C	10		
	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2	.,,	
Maximum required DC gate voltage to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	1		
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V	
Maximum DC gate voltage not to trigger	V_{GD}	I _J = 125 °C, V _{DRM} = Rated value			
Maximum DC gate current not to trigger	I _{GD}			mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8	
Typical reverse recovery time	t _{rr}	T _ 105 °C	3	μs
Typical turn-off time	t _q	T _J = 125 °C	100	



www.vishay.com

Vishay Semiconductors

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque —	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220AB	12TT	TS08

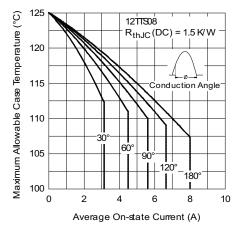


Fig. 1 - Current Ratings Characteristics

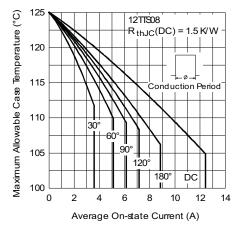


Fig. 2 - Current Ratings Characteristics

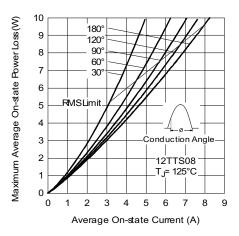


Fig. 3 - On-State Power Loss Characteristics

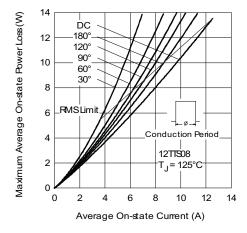


Fig. 4 - On-State Power Loss Characteristics

Vishay Semiconductors

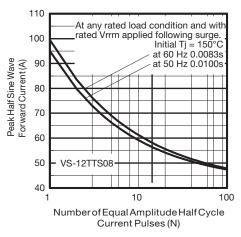


Fig. 5 - Maximum Non-Repetitive Surge Current

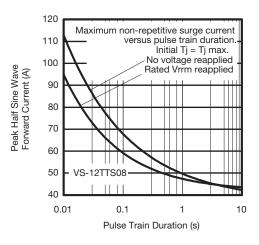


Fig. 6 - Maximum Non-Repetitive Surge Current

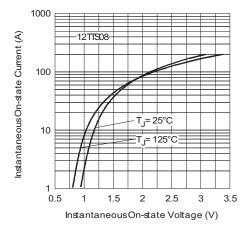


Fig. 7 - On-State Voltage Drop Characteristics

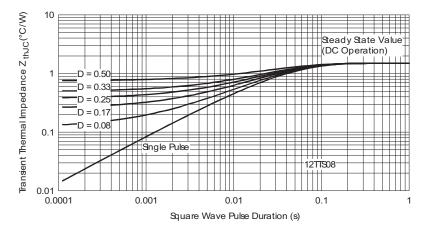


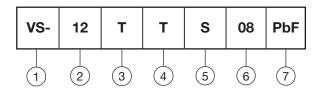
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

VS-12TTS08PbF, VS-12TTS08-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current ratings (12 = 12.5 A)

3 - Circuit configuration:

T = Single thyristor

4 - Package:

T = TO-220

5 - Type of silicon

S = Standard recovery rectifier

6 - Voltage rating (08 = 800 V)

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-12TTS08PbF	50	1000	Antistatic plastic tubes	
VS-12TTS08-M3	50	1000	Antistatic plastic tubes	

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -M3	www.vishay.com/doc?95028		



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

VS-12TTS08PBF 12TTS08S